NSN 5961-01-109-0653

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-109-0653 **Inclosure Material:** Glass **Overall Length:** 0.430 inches **Overall Diameter:** 0.850 inches **Mounting Method:** Press fit Voltage Rating In Volts Per Characteristic: 2.5 gate trigger voltage, dc **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 110.0 degrees celsius ambient air Shelf Life: N/a **Unit Of Measure:** Demilitarization: Yes - demil/mli

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